

Electronic Supplementary Information (ESI)

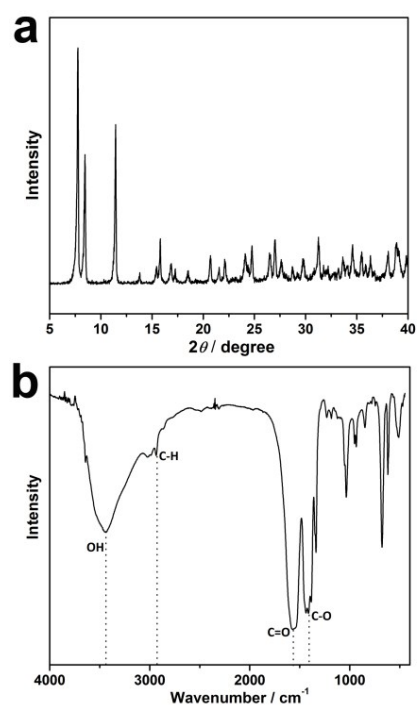


Fig. S1 (a) XRD pattern of the Ni-Mn precursors, (b) FTIR spectra of the Ni-Mn precursors.

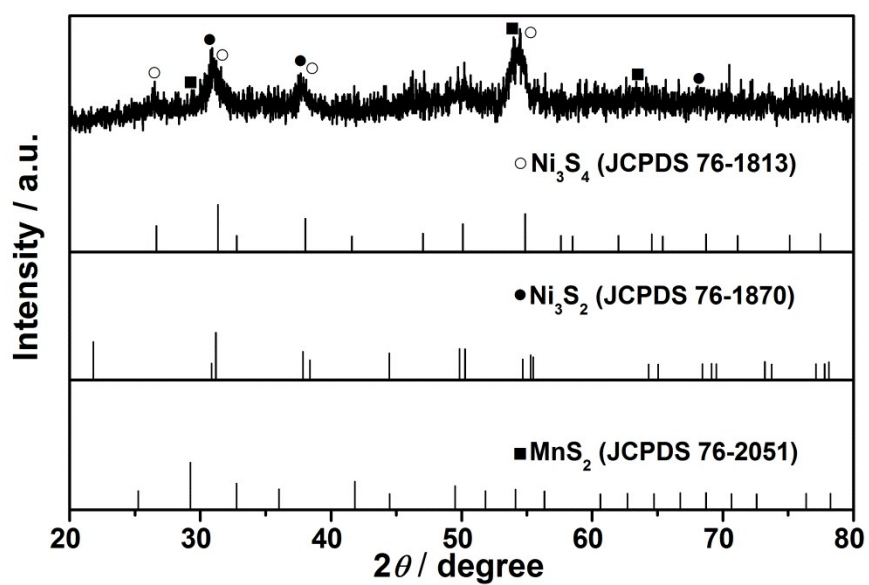


Fig. S2 XRD patterns of the synthesized hollow ellipsoids Ni-Mn sulfides.

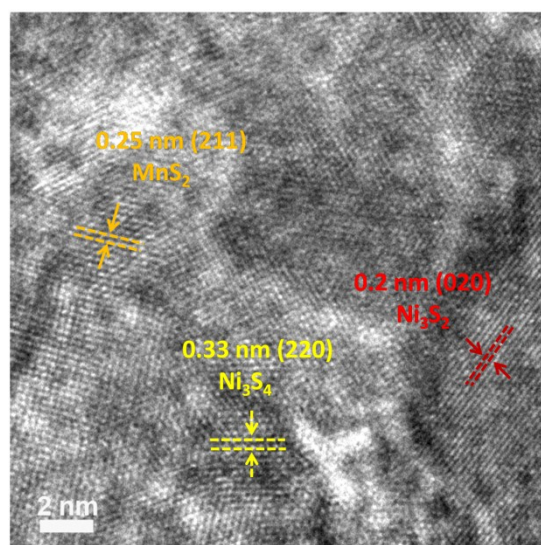


Fig. S3 High-resolution TEM image of the hollow ellipsoids Ni-Mn sulfides.

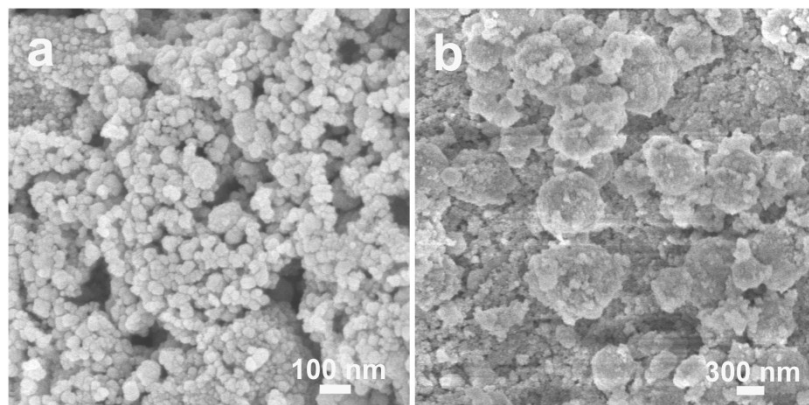


Fig. S4 SEM images of the nickel sulfide (a) and manganese sulfide (b).

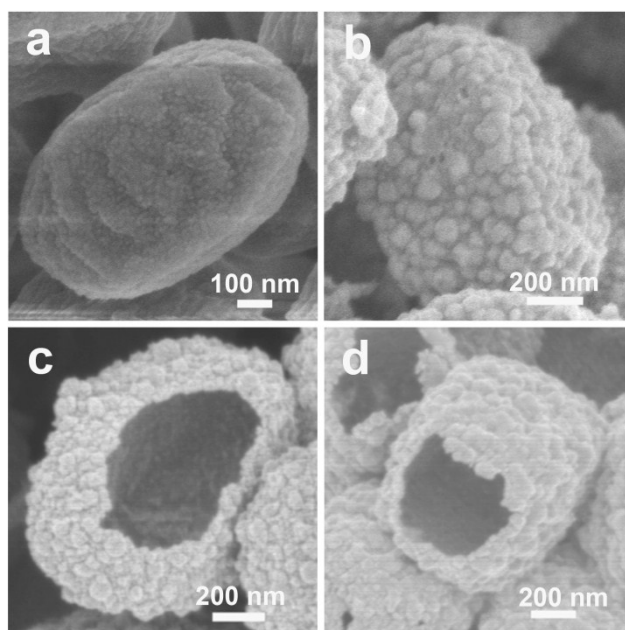


Fig. S5 Products obtained after sulfidation of the solid ellipsoids Ni-Mn precursors at 120 °C for different durations: (a) 30min, (b) 50 min, (c) 80 min, (d) 120 min.

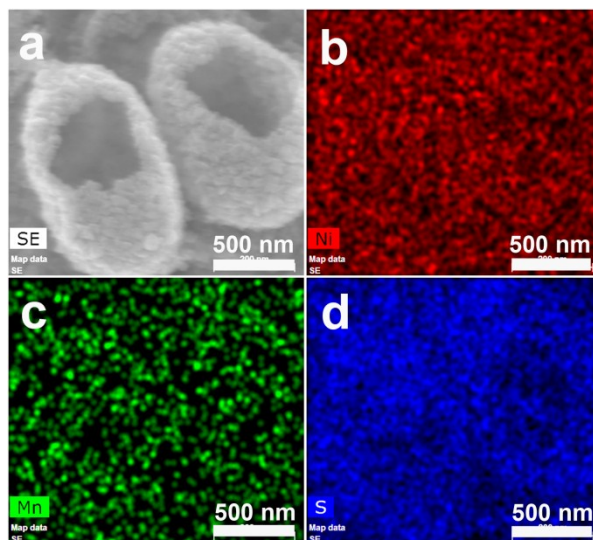


Fig. S6 (a) FESEM image of hollow ellipsoids Ni-Mn sulfides and corresponding elemental mapping images: (b) Ni, (c) Mn and (d) S.

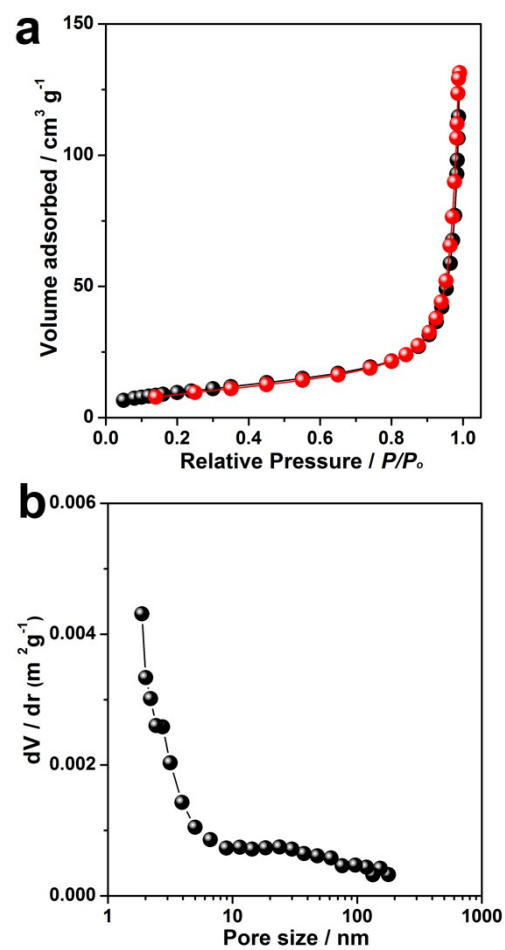


Fig. S7 (a) the N_2 adsorption-desorption isotherm and (b) pore size distribution of hollow ellipsoids Ni-Mn sulfides.

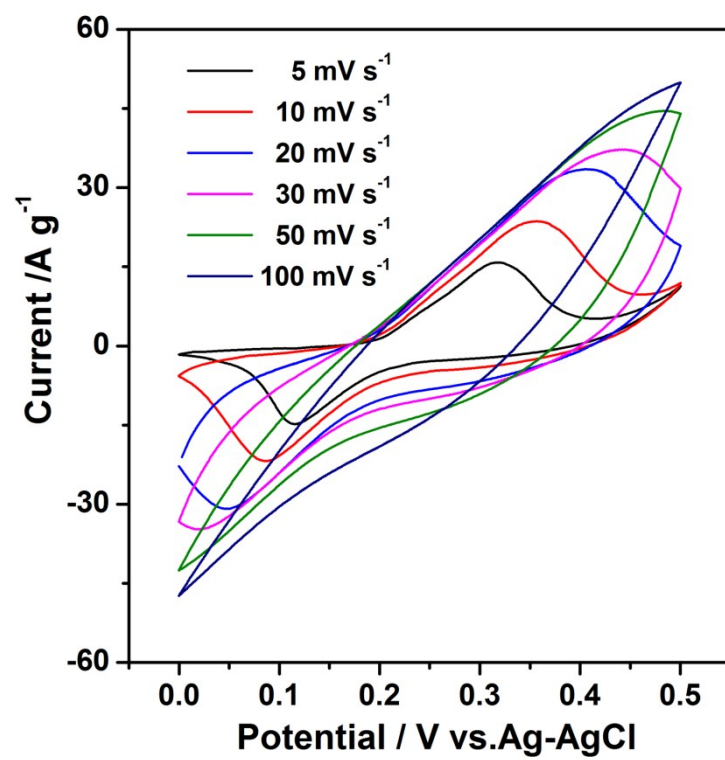


Fig. S8 CV curves of hollow ellipsoids Ni-Mn sulfides at different scan rates.

Table.S1 Comparison specific capacitances of hollow ellipsoids Ni-Mn sulfides with other hybrid metal oxides/sulfides.

Electrode materials	Specific capacitance	References
ZnO-NiO hollow spheres	497 F g ⁻¹ at 1.3 A g ⁻¹	60
Co ₃ O ₄ /CeO ₂ nanowire arrays	1037.5 F g ⁻¹ at 2.0 A g ⁻¹	61
Hollow spiny Ni-Mn oxides	1140F g ⁻¹ at 1.0 A g ⁻¹	62
Co-Ni-Mn oxide nanowires	554 F g ⁻¹ at 2.0 A g ⁻¹	63
Hierarchical NiCo ₂ O ₄	816 F g ⁻¹ at 2.0 A g ⁻¹	64
Mn-Ni-Co oxide nanowires	638 F g ⁻¹ at 1.0 A g ⁻¹	65
ZnO@ZnS core-shell arrays	603.8 F g ⁻¹ at 2.0 A g ⁻¹	66
ZnS-NiS ₂ hollow spheres	970 F g ⁻¹ at 2.0 A g ⁻¹	67
NiCo ₂ S ₄ /Co ₉ S ₈ hollow spindles	749 F g ⁻¹ at 4.0 A g ⁻¹	68
Ni ₂ CoS ₄ nanoboxes	1200 F g ⁻¹ at 2.0 A g ⁻¹	69
3D hierarchical Ni-Co sulfides	276.7 F g ⁻¹ at 0.5 A g ⁻¹	70
Hedgehog-like hollow Ni-Mn sulfides	1176 F g ⁻¹ at 2.0 A g ⁻¹	40
Hollow ellipsoids Ni-Mn sulfides	1636.8 F g ⁻¹ at 2.0 A g ⁻¹	This work

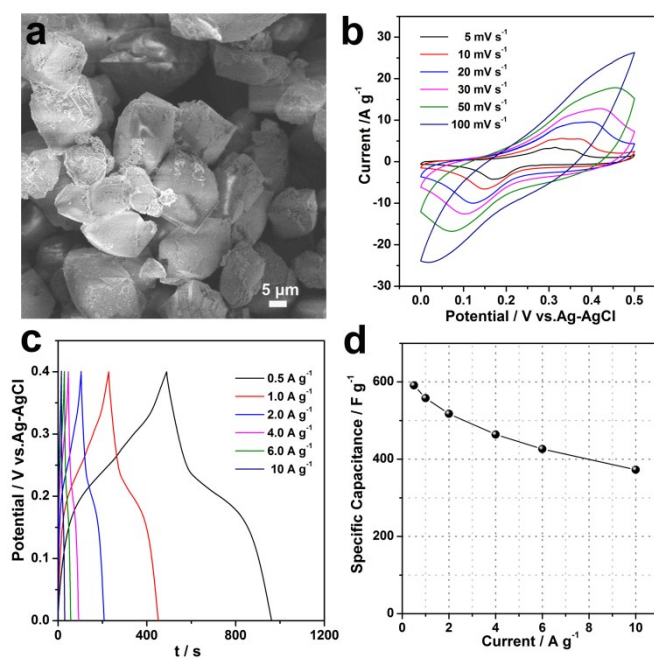


Fig. S9 (a) SEM image of the solid Ni-Mn sulfides, (b) CV curves at scanning rates from 5 to 100 mV s^{-1} , (c) CA curves at current densities from 0.5 to 10 A g^{-1} , (d) Specific capacitance at current densities from 0.5 to 10 A g^{-1} .

Table. S2 Performance comparison of the hollow ellipsoids Ni-Mn sulfides/GCE with other glucose sensors.

Sensing materials	Linear range (μM)	Detection limit (μM)	References
Honeycomb-like Ni@C composites	2-280	0.9	17
α -NiS hollow spheres	0.125-200	0.08	72
Lithium-doped NiO nanofibers	0.5-278	0.1	73
Copper oxide nanostructures	0.01-10	1.37	74
Reduced graphene oxide/ZnO	0.02-22.48	0.02	75
Nafion/Cu ₂ O	0.002-0.35	1.3	76
Hierarchically porous NaCoPO ₄ -Co ₃ O ₄ hollow microspheres	1.0-26	0.125	77
Hollow ellipsoids Ni-Mn sulfides	0.05-500	0.02	This work

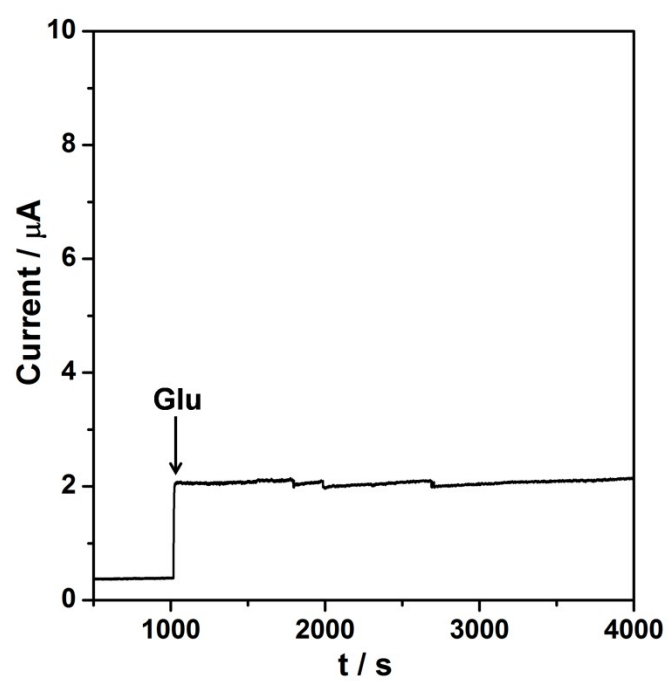


Fig. S10 The stability of the response current for hollow ellipsoids Ni-Mn sulfides/GCE sensors after the addition of 40 μM glucose.

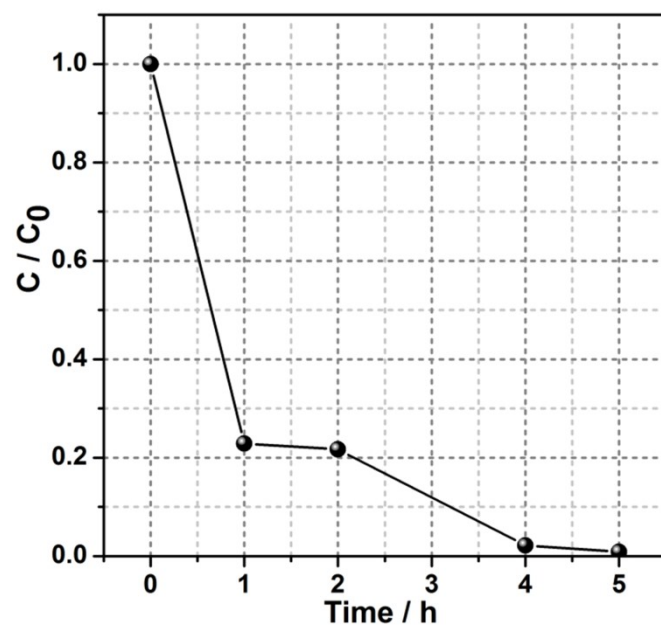


Fig. S11 Curves of the adsorption extent of Congo red as a function of contact time for hollow ellipsoids Ni-Mn sulfides.

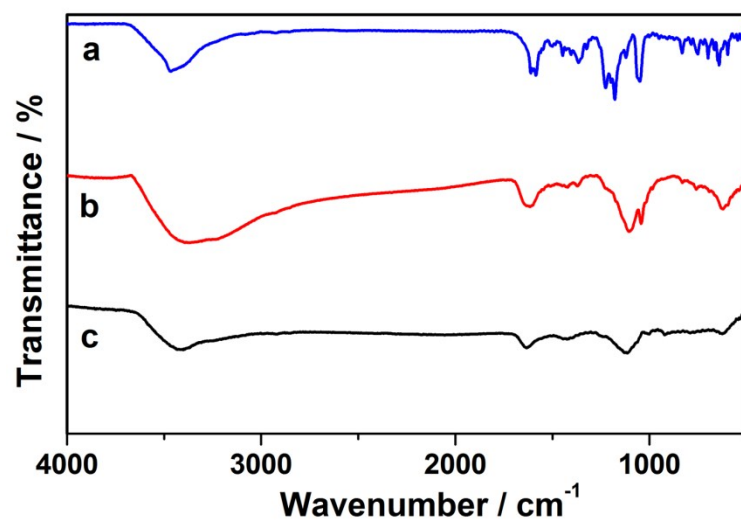


Fig. S12 IR spectra of Congo red (a), hollow ellipsoids Ni-Mn sulfides after water purification (b) and (c) hollow ellipsoids Ni-Mn sulfides.